## PATENT APPLICATION

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of

Etienne QUESNEL et al.

Application No.: New U.S. Patent Application

Filed: April 5, 2004 Docket No.: 119364

For: PROCESS DESIGNED TO PREVENT DEPOSITION OF CONTAMINATING PARTICLES ON THE SURFACE OF A MICRO-COMPONENT, MICRO-COMPONENT

STORAGE DEVICE AND THIN LAYER DEPOSITION DEVICE

## **INFORMATION DISCLOSURE STATEMENT**

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

Pursuant to 37 CFR §1.56, the attention of the Patent and Trademark Office is hereby directed to the reference(s) listed on the attached PTO-1449. Unless otherwise indicated herein, one copy of each reference is attached. It is respectfully requested that the information be expressly considered during the prosecution of this application, and that the reference(s) be made of record therein and appear among the "References Cited" on any patent to issue therefrom.

- 1. This Information Disclosure Statement is being filed (a) within three months of the U.S. filing date of this non-CPA application, OR (b) before the mailing date of a first Office Action on the merits in the present application. No certification or fee is required.
- 2. Relevance of reference No. 4 is discussed in the present specification.
- 3. The references were cited in a counterpart foreign application. An English language version of the foreign search report is attached for the Examiner's information.
- 4. The present application was filed or entered the U.S. National Stage of the PCT after June 30, 2003. In accordance with the June 11, 2003, Notice waiving the requirements of 37 CFR §1.98(a)(2)(i), copies of any U.S. patents and patent application publications are not attached.

- 5. An English-language Abstract of non-English language reference No. 2 is attached hereto.
- 6. A computer-generated English translation of the following Japanese Patent Publication has been obtained from the website of the Japanese Patent Office ([http://www.jpo.go.jp]), and is attached, but has not been reviewed for accuracy. See Reference 2.

Respectfully submitted,

William P. Berridge Registration No. 30,024

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WPB:JSA/mxm

Date: April 5, 2004

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Form PTO-1449 US Dept. of Commerce (REV. 8-83) PATENT & TRADEMARK OFFICE				ATTY DOCKET NO. 119364			APPLICATION NO. New U.S. Patent Application		
INFORMATION DISCLOSURE STATEMENT									<b>F.F</b>
(Use several sheets if necessary)				APPLICANTS Etienne QUESNEL et al.					
					DATE 2004				
		U.S.	PAT	ENT DOCL	JMENTS				
EXAMINER INITIAL		DOCUMENT NUMBER	DATE 7/12/1983			NAME		CLASS	SUB CLASS
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	2	JP A 7-291790 w/ Abst & Trans	11/	7/1995	Japan				
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OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)

3 KOJIMA et al. "IMPURITY GENERATION FOR LOW ENERGY RANGE OF ION BOMBARDMENT AND ITS
TRANSPORT IN A PLASMA," Journal of Nuclear Materials 241-243 (1997), pp. 1248-1252.

4 WALTON et al. "EXTREME ULTRAVIOLET LITHOGRAPHY - REFLECTIVE MASK TECHNOLOGY," Emerging
Lithographic Technologies IV, Proceedings of SPIE Vol. 3997 (2000) pp. 496-507.

5 HUE et al. "REDUCTION OF DEFECT DENSITY ON BLANKS: APPLICATION TO THE EXTREME
ULTRAVIOLET LITHOGRAPHY," Microelectric Engineering 61-62 (2002), pp. 203-211.

EXAMINER:

DATE CONSIDERED

conformance and not considered. Include copy of this form with next communication to applicant.

Initial if citation considered, whether or not citation is in conformance with M.P.E.P. 609; draw line through citation if not in

Date: April 5, 2004

Examiner: